

# MDM900E17D

## FEATURES

- \* Low noise due to ultra soft fast recovery diode.
- \* High reliability, high durability diodes.
- \* Isolated heat sink (terminal to base).

## ABSOLUTE MAXIMUM RATINGS (T<sub>C</sub>=25°C)

Item	Symbol	Unit	MDM900E17D
Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	V	1,700
Forward Current	DC	A	900
	1ms		1,800
Operating Junction Temperature	T <sub>vj op</sub>	°C	-40 ~ +125
Storage Temperature	T <sub>stg</sub>	°C	-40 ~ +125
Isolation Test Voltage	Terminals-base	V <sub>ISO</sub>	V <sub>RMS</sub>
	Terminal 1-Terminal 2		
Screw Torque	Terminals (M8)	-	N·m
	Mounting (M6)		
			6 (2)

Notes: (1) Recommended Value 15<sup>+0</sup>.<sub>3</sub>N·m

(2) Recommended Value 5.5±0.5N·m

## ELECTRICAL CHARACTERISTICS

Item	Symbol	Unit	Min.	Typ.	Max.	Test Conditions
Repetitive Reverse Current	I <sub>RRM</sub>	mA	-	1.0	10.0	V <sub>AK</sub> =1,700V, V <sub>GE</sub> =0V, T <sub>vj</sub> =125°C
Forward Voltage Drop	V <sub>F</sub>	V	1.5	2.0	2.5	I <sub>F</sub> =900A, T <sub>vj</sub> =125°C
Reverse Recovery Time	t <sub>rr</sub>	μs	-	0.7	1.4	V <sub>CC</sub> =900V, I <sub>F</sub> =900A, L <sub>s</sub> =180nH R <sub>G</sub> =1.5Ω, T <sub>vj</sub> =125°C (3)(Fig.1)
Reverse Recovery Loss	E <sub>rr(10%)</sub>	J/P	-	0.4	0.7	(Type test)
Reverse Recovery Time(2)	t <sub>rr(2)</sub>	μs	-	0.7	1.4	V <sub>CC</sub> =900V, I <sub>F</sub> =1800A, L <sub>s</sub> =80nH R <sub>G</sub> =1.5Ω, T <sub>vj</sub> =125°C (3)(Fig.1)
Reverse Recovery Loss(2)	E <sub>rr(full)(2)</sub>	J/P	-	0.8	1.4	(Routine test)

Notes: (3) Counter arm: MBN2400E17D V<sub>GE</sub>= ±15VR<sub>G</sub> are the test condition's value to define the switching characteristics not recommended value.Please, determine the suitable R<sub>G</sub> value after the measurement of switching waveforms (overshoot voltage, etc.) with appliance mounted.

## PACKAGE CHARACTERISTICS

Item	Symbol	Unit	Min.	Typ.	Max.	Test Conditions
Terminal Resistance	R <sub>CE</sub>	mΩ	-	0.4	-	per arm, T <sub>vj</sub> =25°C
Stray inductance module	L <sub>SCE</sub>	nH	-	35	-	per arm
Thermal Impedance	R <sub>th(j-c)</sub>	K/W	-	-	0.045	Junction to case (par arm)
Contact Thermal Impedance	R <sub>th(c-f)</sub>	K/W	-	0.008	-	Case to fin (par module)

\* Please contact our representatives at order.

\* For improvement, specifications are subject to change without notice.

\* For actual application, please confirm this spec sheet is the newest revision.

# MDM900E17D

## DEFINITION OF TEST CIRCUIT

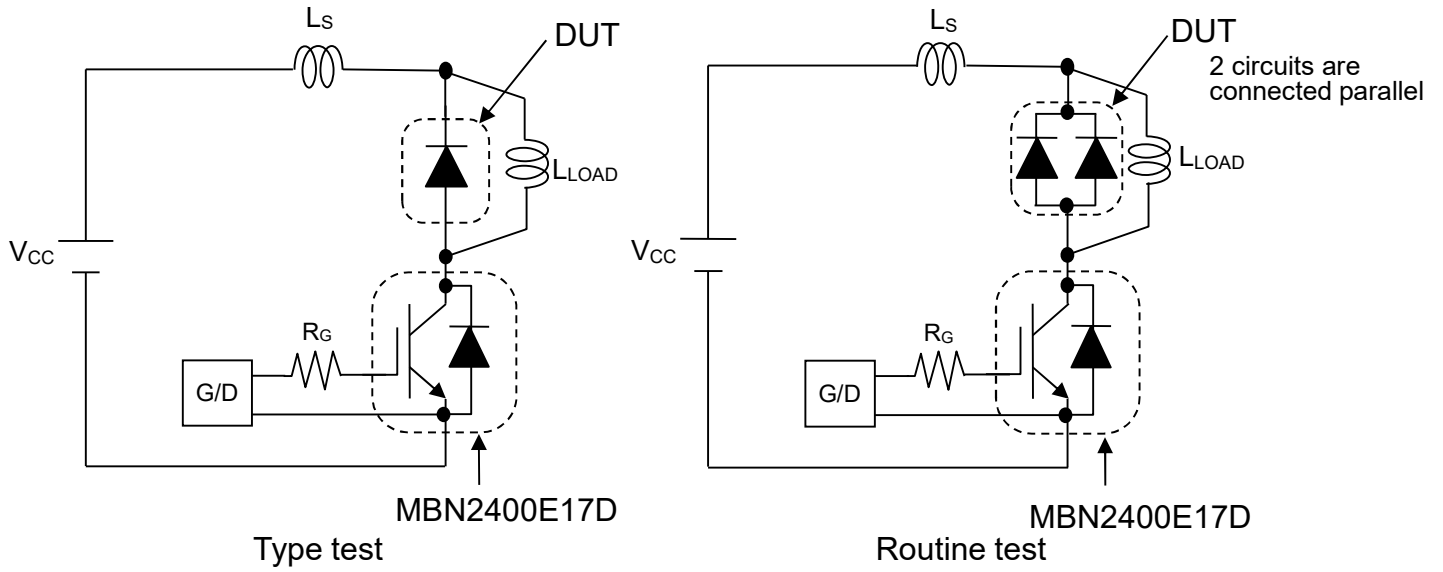


Fig.1 Switching test circuit

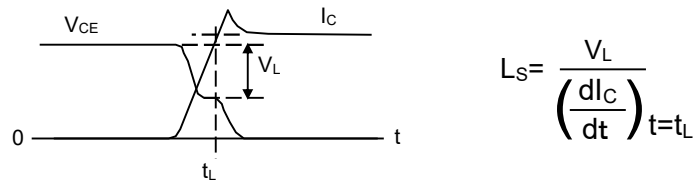
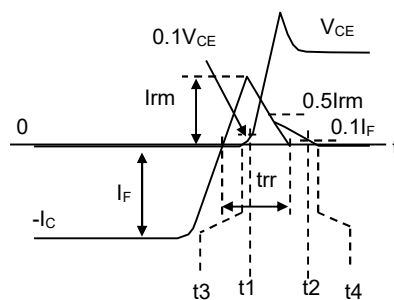


Fig.2 Definition of stray inductance



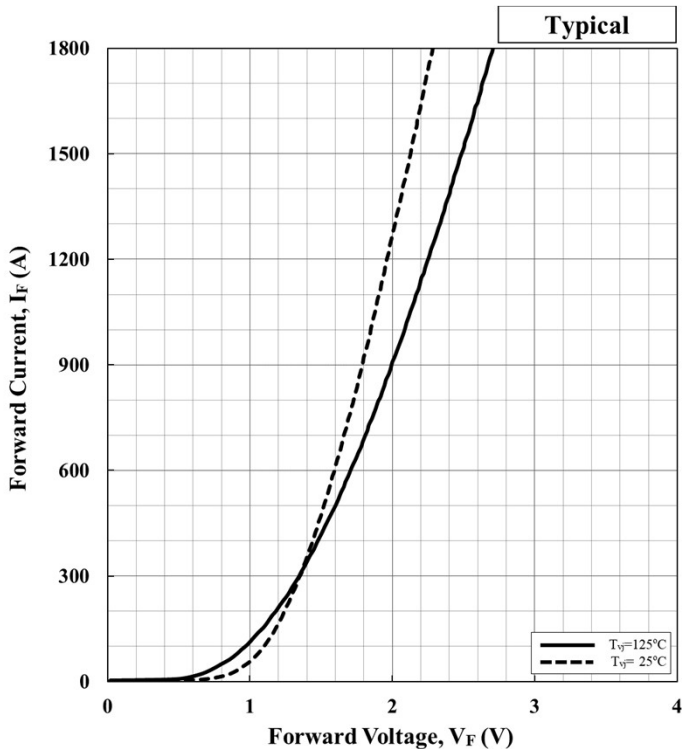
$$E_{rr(10\%)} = \int_{t1}^{t2} I_F \cdot V_{CE} dt$$

$$E_{rr(full)} = \int_{t3}^{t4} I_F \cdot V_{CE} dt$$

Fig.3 Definition of switching loss



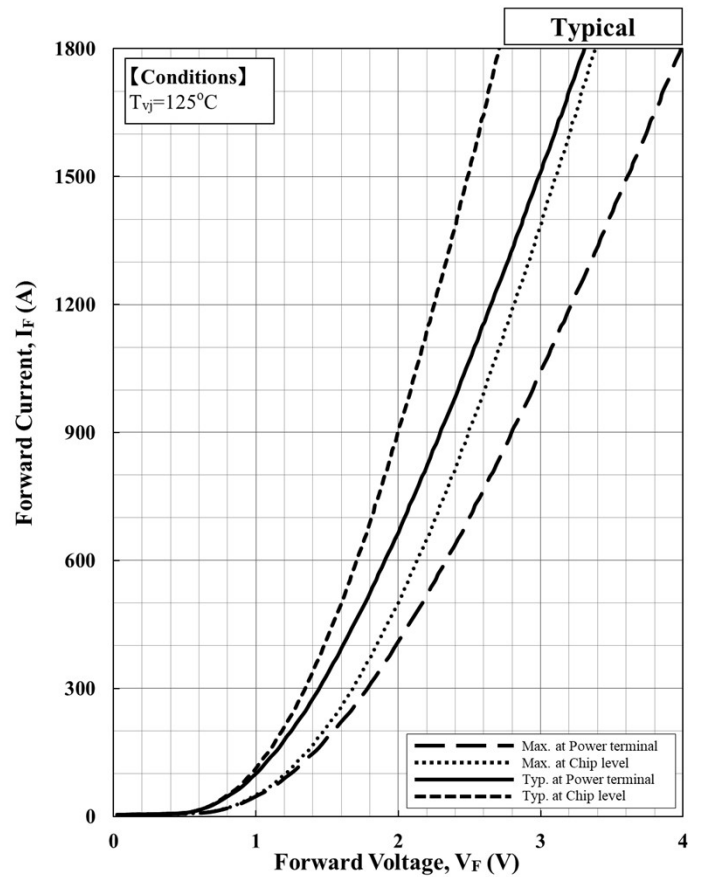
# MDM900E17D



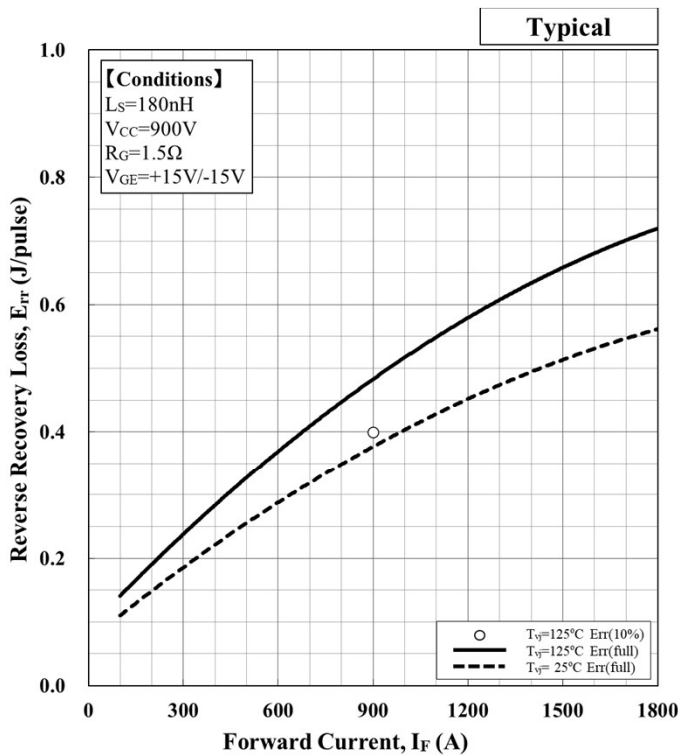
$$V_F[V] = a_3 \cdot |I_F|^3 + a_2 \cdot |I_F|^2 + a_1 \cdot |I_F| + a_0$$

Temp.[°C]	$a_3$	$a_2$	$a_1$	$a_0$
25	1.30E-10	-5.52E-07	1.29E-03	9.92E-01
125	1.91E-10	-8.28E-07	1.92E-03	8.12E-01

Forward Current vs. Forward Voltage (at chip level)



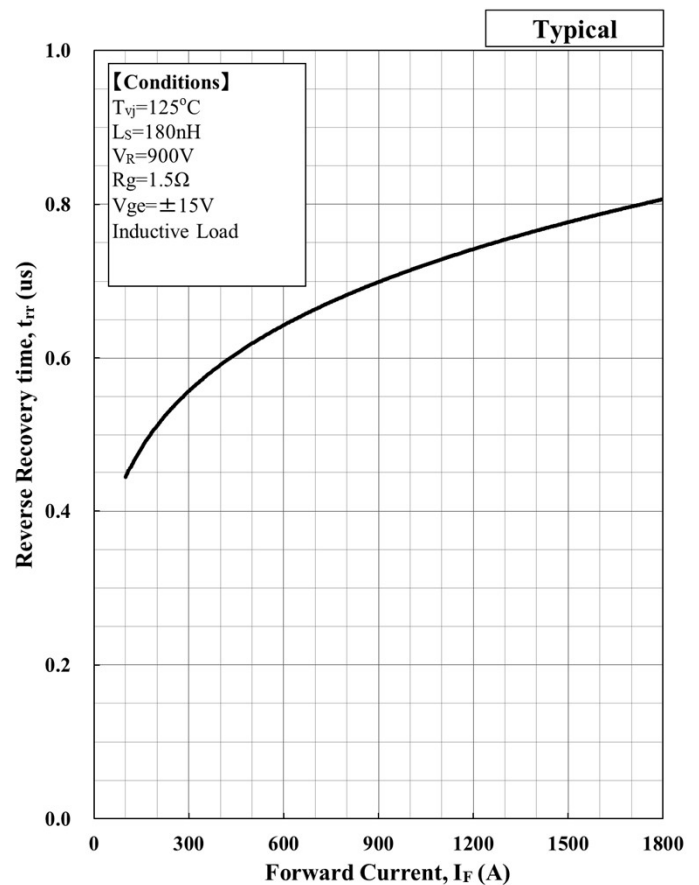
Forward Current vs. Forward Voltage



$$E [J] = a_3 \cdot |I_F|^3 + a_2 \cdot |I_F|^2 + a_1 \cdot |I_F| + a_0$$

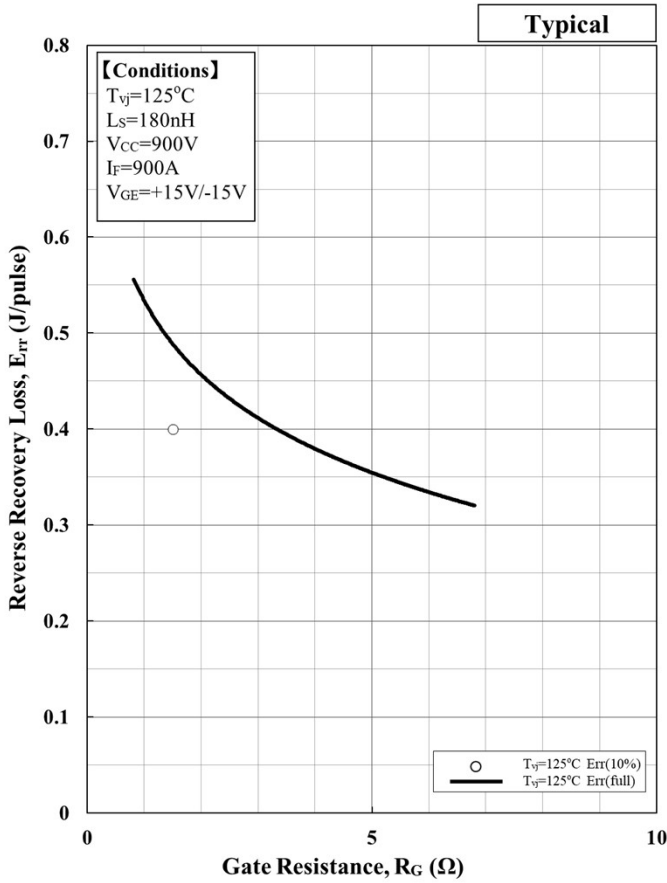
Temp.[°C]	$a_3$	$a_2$	$a_1$	$a_0$
25	-	-7.54E-08	4.09E-04	6.98E-02
125	-	-9.67E-08	5.24E-04	8.95E-02

Recovery loss vs. Forward current

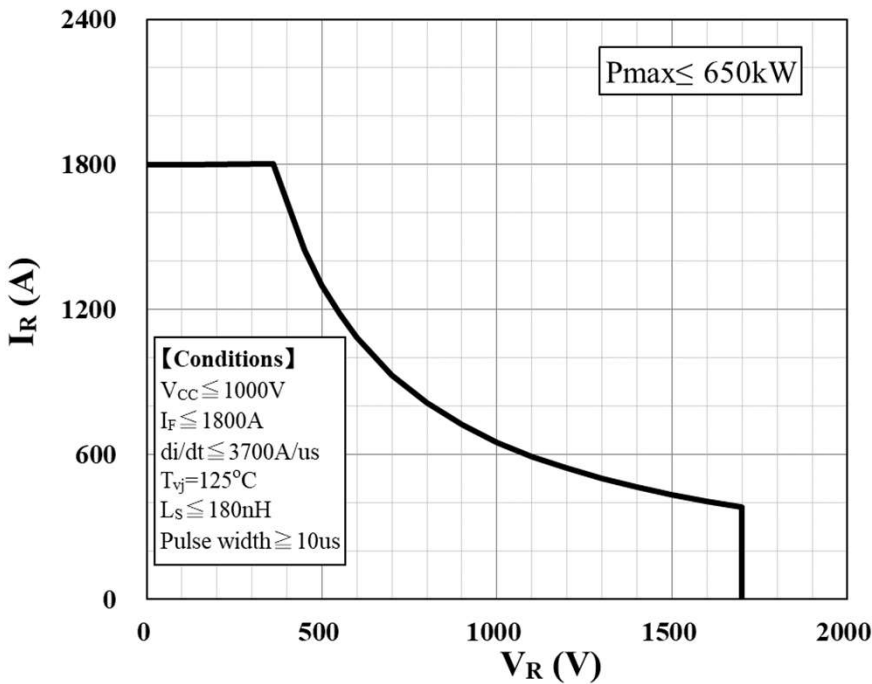


Reverse Recovery time vs. Forward Current

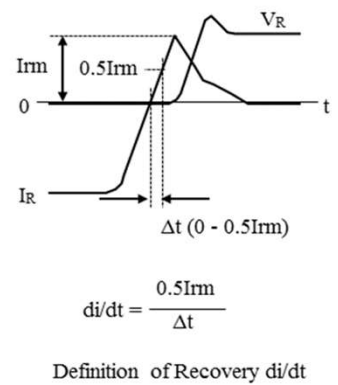
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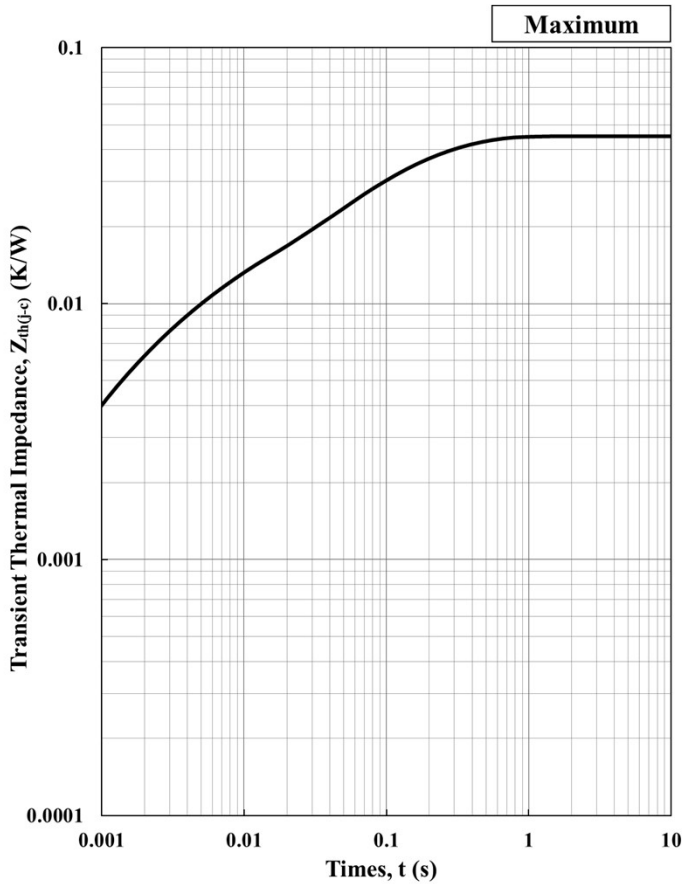
Reverse Recovery loss vs. Gate Resistance



(Defined at power terminals)  
 Reverse Recovery Safe Operation Area ( RRSOA )



# MDM900E17D



**Transient Thermal Impedance Curve**

Foster model lumped circuit constant

n	1	2	3	4	Unit
R th, Diode [n]	2.01E-02	1.44E-02	7.53E-03	2.97E-03	[K/W]
C th, Diode [n]	1.05E+01	3.65E+00	5.56E-01	2.88E-01	[J/K]

Cauer model lumped circuit constant

n	1	2	3	4	Unit
R th, Diode [n]	7.07E-03	7.38E-03	2.07E-02	9.85E-03	[K/W]
C th, Diode [n]	1.77E-01	5.01E-01	2.50E+00	1.68E+01	[J/K]

**Material declaration**

Please note the following materials are contained in the product, in order to keep characteristic and reliability level.

Material	Contained part
Lead (Pb) and its compounds	Solder

# MDM900E17D

## Minebea POWER SEMICONDUCTORS

### Notices

1. Since mishandling of semiconductor devices may cause malfunctions, please be sure to read "Precautions for Safe Use and Notices" in the individual brochure before use.
2. When designing an electronic circuit using semiconductor devices, please do not exceed the absolute maximum rating specified for the device under any external fluctuations. And for pulse applications, please also do not exceed the "Safe Operating Area (SOA)".
3. Semiconductor devices may sometimes break down by accidental or unexpected surge voltage, so please be careful about the safety design such as redundant design and malfunction prevention design which don't cause the damage expand even if they break down.
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5. A semi-processed article is done now using solder which contains lead inside the semiconductor devices. There is possibility of the regulation substance depend on the applied models, so please check before using.
6. This specification is a material for component selection, which describes specifications of power semiconductor devices (hereinafter referred to as products), characteristic charts, and external dimension drawings.
7. The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact with Minebea power semiconductor sales department for the latest version of this data sheets.
8. For handling other than described in this manual, follow the handling instructions (IGBT-HI-00002).

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# MDM900E17D

## Minebea POWER SEMICONDUCTORS

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